TT2148



Switching Regulator Applications

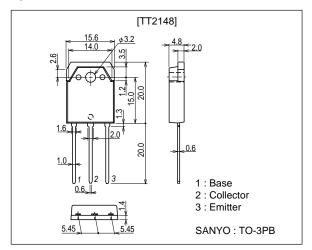
Preliminary

Features

- · High breakdown voltage and high reliability.
- · Fast switching speed.
- · Wide ASO.
- · Adoption of MBIT process.

Package Dimensions

unit : mm 2022A



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		500	V
Collector-to-Emitter Voltage	VCEO		400	V
Emitter-to-Base Voltage	VEBO		7	V
Collector Current	IC		12	Α
Collector Current (Pulse)	ICP	PW≤300μs, Duty Cycle≤10%	20	Α
Base Current	ΙΒ		3.5	Α
Collector Dissipation	Do.		2.5	W
	PC	Tc=25°C	80	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
i arameter	Symbol	Conditions	min	typ	max	Offic
Collector Cutoff Current	ІСВО	V _{CB} =400V, I _E =0			10	μΑ
Emitter Cutoff Current	IEBO	V _{EB} =5V, I _C =0			10	μΑ

Continued on next page.

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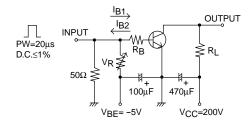
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Parameter	Symbol	Conditions	Ratings			Unit
Falametei	Symbol	Conditions	min	typ	max	1 Offic
	hFE1	V _{CE} =5V, I _C =1.2A	20*		50*	
DC Current Gain	hFE2	V _{CE} =5V, I _C =6A	10			
	hFE3	V _{CE} =5V, I _C =1mA	10			
Gain-Bandwidth Product	fT	V _{CE} =10V, I _C =1.2A		20		MHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		120		pF
Collector-to-Emitter Saturation Voltage	VCE(sat)	IC=6A, IB=1.2A			0.8	V
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	I _C =6A, I _B =1.2A			1.5	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=1mA, IE=0	500			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=5mA, R _{BE} =∞	400			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	IE=1mA, IC=0	7			V
Turn-ON Time	ton	I _C =7A, I _{B1} =1.4A, I _{B2} =-2.8A, R _L =28.6Ω, V _{CC} =200V			0.5	μs
Storage Time	tstg	I _C =7A, I _{B1} =1.4A, I _{B2} =-2.8A, R _L =28.6Ω, V _{CC} =200V			2.5	μs
Fall Time	tf	I _C =7A, I _{B1} =1.4A, I _{B2} =-2.8A, R _L =28.6Ω, V _C C=200V			0.3	μs

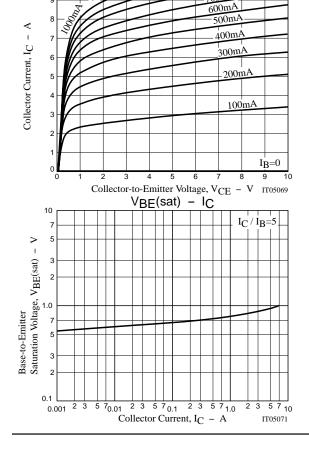
* : The hFE1 o	of the TT2148	is classified	l as follows.

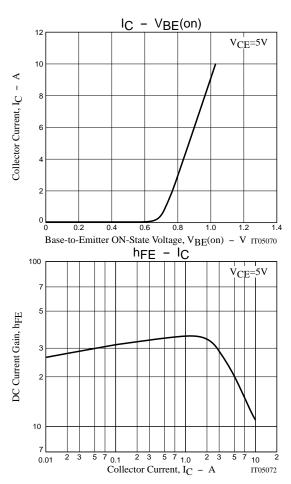
Rank	М	N
hFE	20 to 40	30 to 50

Switching Time Test Circuit

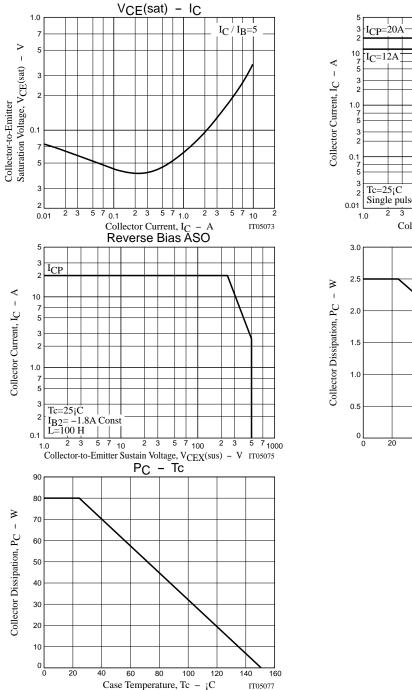


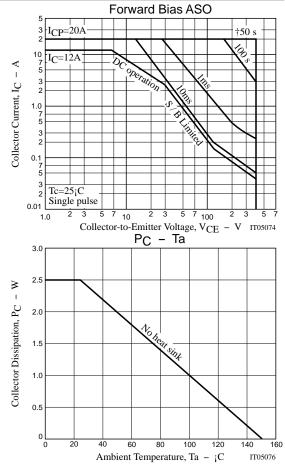
IC - VCE





No.0000-2/4





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